

RP130x121x

SPICE Modeling Report

No. SPM-RP130x121x_C,YC-210902

Terms of Use for SPICE Model

- 1. Introduction
 - This SPICE MODEL is a simulation model and not for use in actual product operation.("Purpose") It is not an alternative to the actual product.
 - Please use this SPICE MODEL to assist in the actual product operation check.
 - Reference information on simulation execution and operating condition for each model may be listed in each net list file, therefore please check before using the SPICE MODEL.
- 2. Terms of Use
 - This SPICE MODEL is a model for the typical characteristics under the ambient temperature condition of 25°C.
- 3. No licensed
 - NISD does not grant any rights, including but not limited to patent or mask works with regards to circuits described in relevant documents.
 - The SPICE MODEL shall be duplicated for the Purpose only.
- 4. Disclaimer
 - NISD shall not be responsible for any changes and inaccuracies caused by the SPICE MODEL.
 - Although NISD strives to ensure that SPICE MODEL works properly, NISD shall not guarantee that the SPICE MODEL operates under all conditions, Computers and simulators.
- X NISD is an abbreviation for Nisshinbo Micro Devices Inc.

SPICE Model

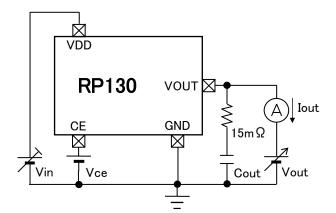
- Library file name...... RP130x121x_C.txt, RP130x121x_YC.lib
- Terminal information

Device Pin No.				Device	vice	Model
DFN(PL)	DFN	SC-82AB	SOT-23-5		Description	Symbol
1010-4	1212 - 4					0,111001
1	1	3	5	V _{OUT}	Output Pin	VOUT
2	2	2	2	GND	Ground Pin	GND
3	3	1	3	CE	Chip Enable Pin ("H" Active)	CE
4	4	4	1	V _{DD}	Input Pin	VDD
_	_	_	4	NC	No Connection	—

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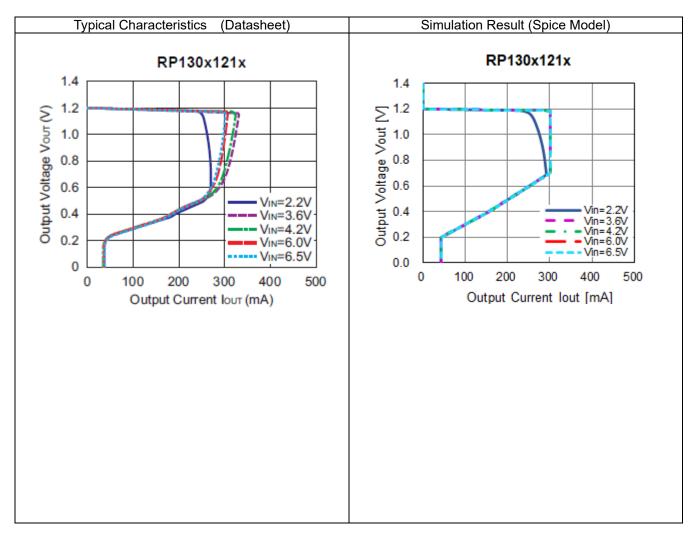
Characteristic Data

Output Voltage vs. Output Current



Condition

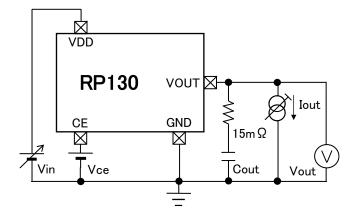
 $\label{eq:Vin} \begin{array}{l} \text{Vin} = 2.2, \ 3.6, \ 4.2, \ 6.0, \ 6.5 \ [V] \\ \text{Vce} = 1.0 \ [V] \\ \text{Cout} = 0.47 \ [\mu\text{F}] \\ \text{Vout} = 0 \ \text{to} \ 1.4 \ [V] \ \text{DC} \ \text{Sweep} \end{array}$



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Characteristic Data

Output Voltage vs. Input Voltage

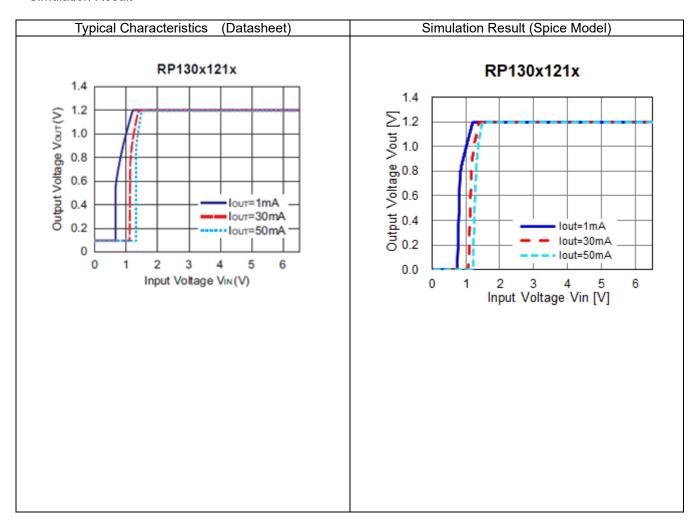


Simulation Result

Condition

 $\label{eq:Vin} \begin{array}{l} \mbox{Vin} = 0 \mbox{ to } 6.5 \ensuremath{\left[V \right]} \ensuremath{\text{DC}} \ensuremath{\text{Sweep}} \\ \mbox{Vce} = 1.0 \ensuremath{\left[V \right]} \\ \mbox{Cout} = 0.47 \ensuremath{\left[\mu F \right]} \\ \mbox{lout} = 1, \ensuremath{\left[30, \ensuremath{\left[50 \ensuremath{\left[m \ensuremath{\left[10 \ensuremath{\left[m \ensuremath{\left[10 \ensuremath{\[10 \ensuremath$

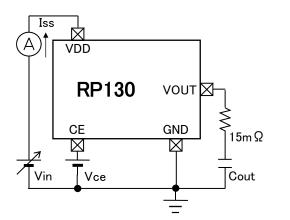
Execute transient simulation with a very slow Vin sweep for stable results.



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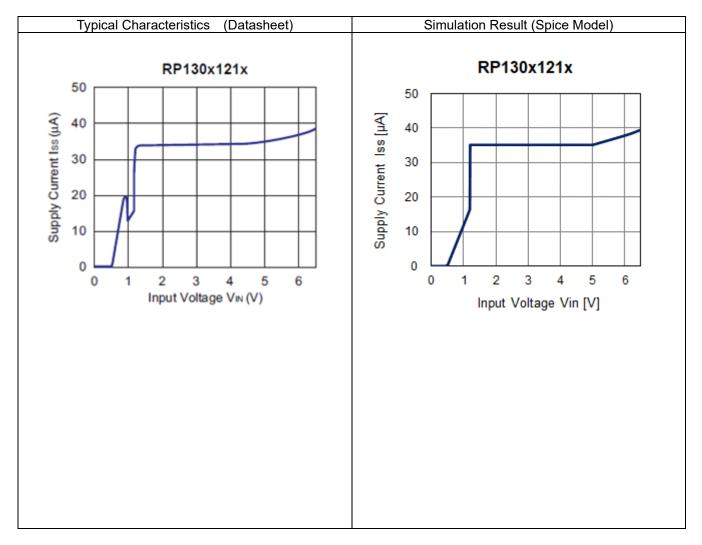
Characteristic Data

Supply Current vs. Input Voltage



Condition

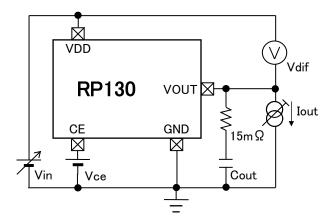
 $\label{eq:Vin} \begin{array}{l} \mbox{Vin} = 0.0 \mbox{ to } 6.5 \mbox{ [V]} \mbox{ DC Sweep} \\ \mbox{Vce} = 1.0 \mbox{ [V]} \\ \mbox{Cout} = 0.47 \mbox{ [}\mu\mbox{F}\mbox{]} \end{array}$



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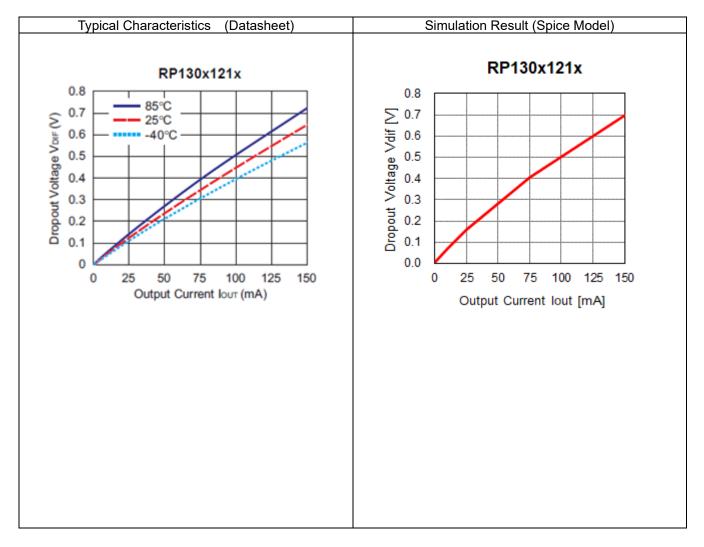
Characteristic Data

Dropout Voltage vs. Output Current



Condition

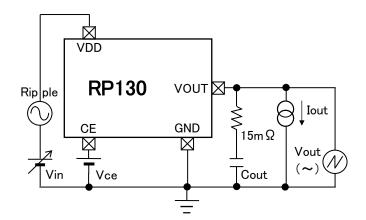
Vin = 0 to 6.5 [V] DC Sweep for each lout (0 to 150[mA]) Vce = 1.0 [V] Cout = 0.47 [µF]



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Characteristic Data

Ripple Rejection vs. Input Bias Voltage

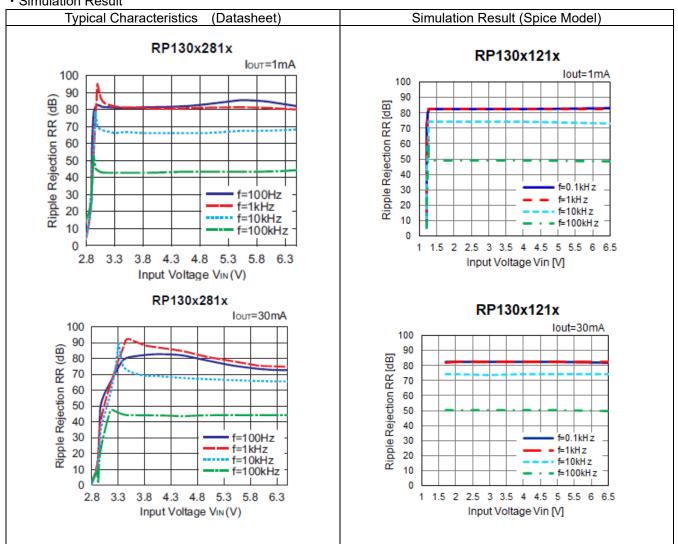


Simulation Result

<u>Condition</u>

 $\label{eq:Vin} \begin{array}{l} \text{Vin} = 1.2 \text{ to } 6.5 \text{ [V] DC Sweep} \\ \text{Vce} = 1.0 \text{ [V]} \\ \text{Cout} = 0.47 \text{ [}\mu\text{F]} \\ \text{lout} = 1, \ 30 \text{ [mA]} \\ \text{Ripple Freq.= 0.1, 1, 10, 100 [kHz]} \\ \text{AC(small signal) sim. was executed.} \end{array}$

Notice; The graph of Typical Characteristics (datasheet) is for the different version from this model.

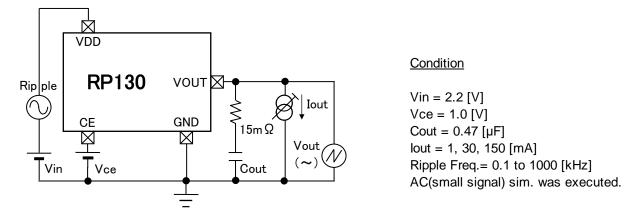


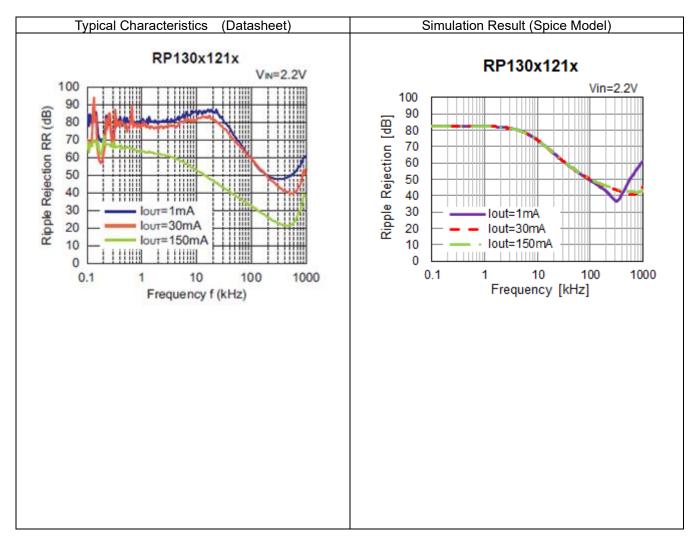
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Characteristic Data

Ripple Rejection vs. Frequency

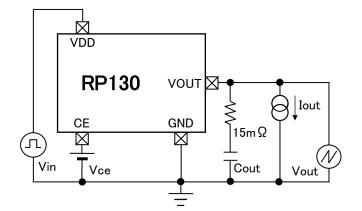




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Characteristic Data

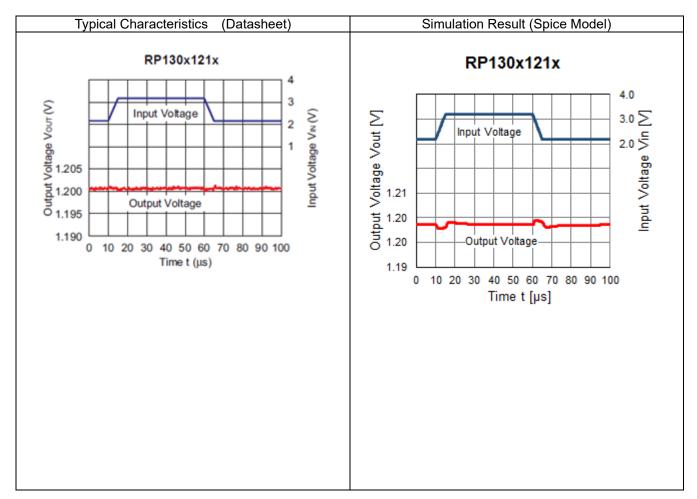
Input Transient Response



Condition

 $\label{eq:Vin} \begin{array}{l} \text{Vin} = 2.2 \rightarrow 3.2 \rightarrow 2.2 \; [\text{V}] \\ \text{tr} = \text{tf} = 5 \; [\mu\text{s}] \\ \text{Vce} = 1.0 \; [\text{V}] \\ \text{Cout} = 0.47 \; [\mu\text{F}] \\ \text{lout} = 30 \; [\text{mA}] \end{array}$

Simulation Result

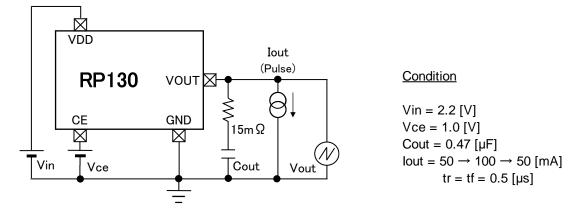


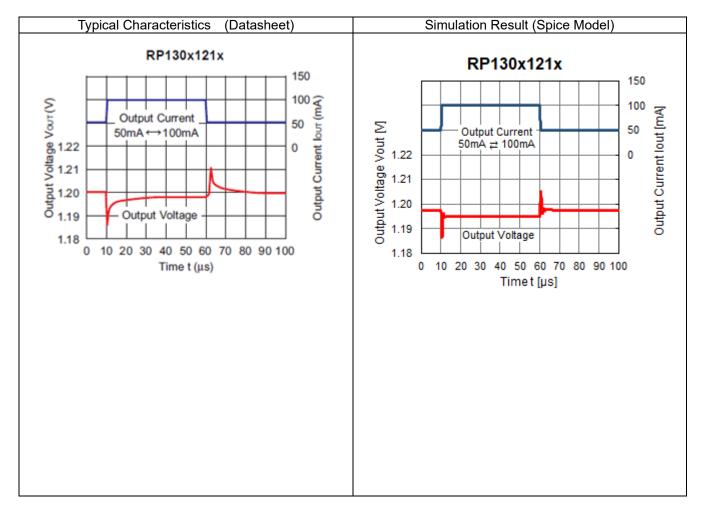
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Characteristic Data

Load Transient Response

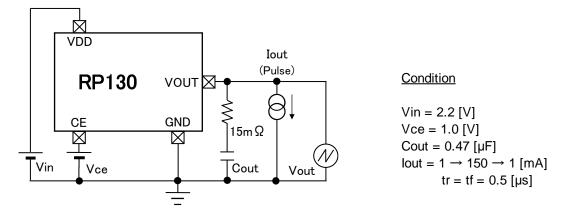


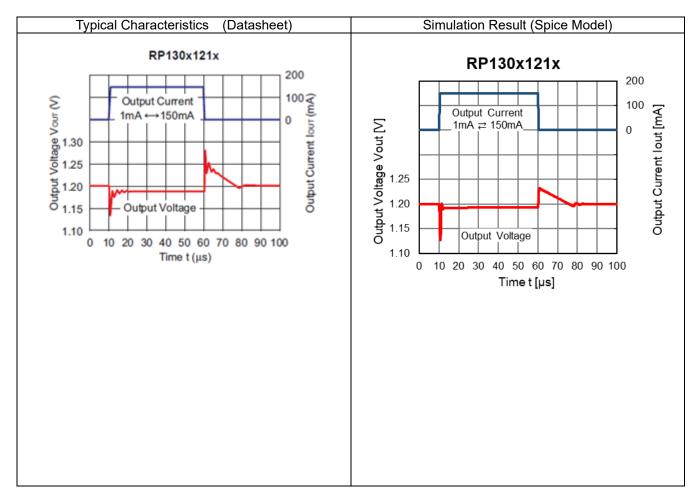


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Characteristic Data

Load Transient Response

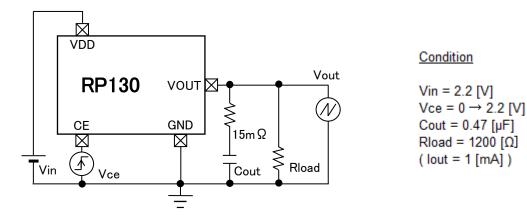


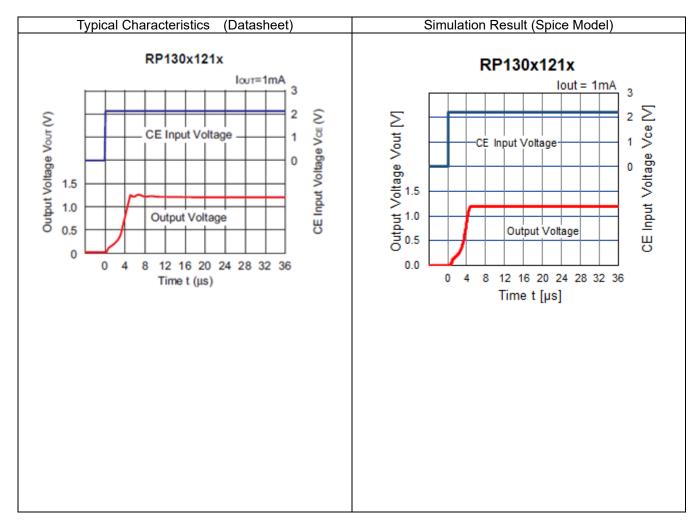


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Characteristic Data

Load Transient Response

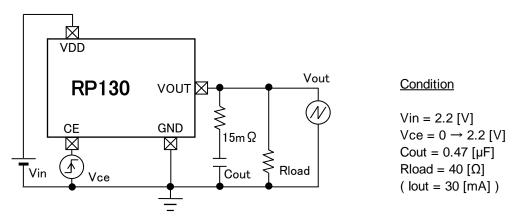


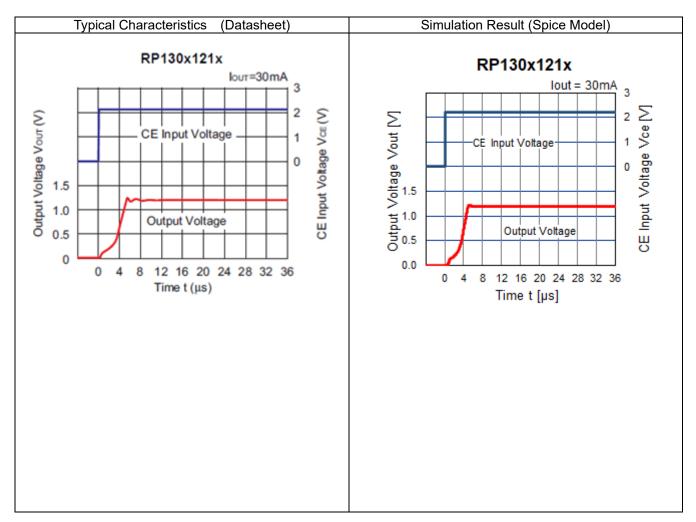


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Characteristic Data

Turn On Speed with CE pin

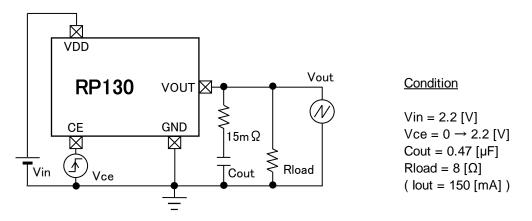


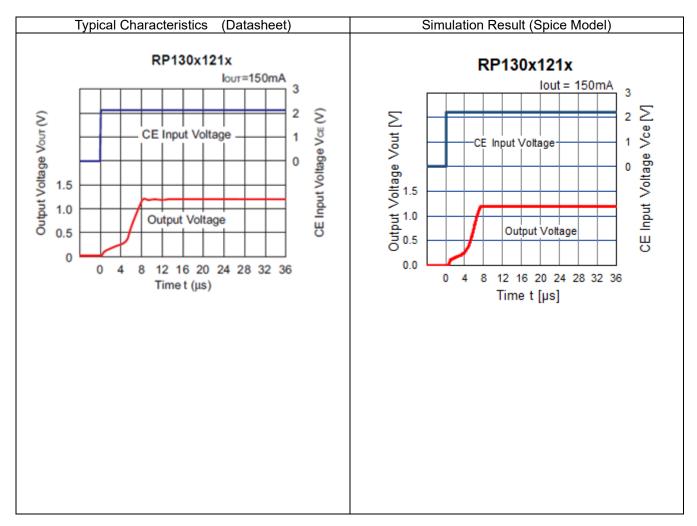


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Characteristic Data

Turn On Speed with CE pin

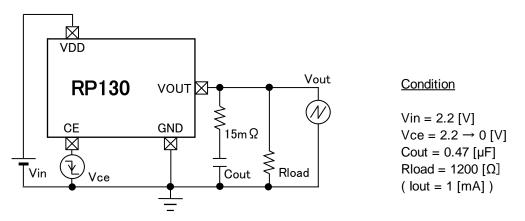




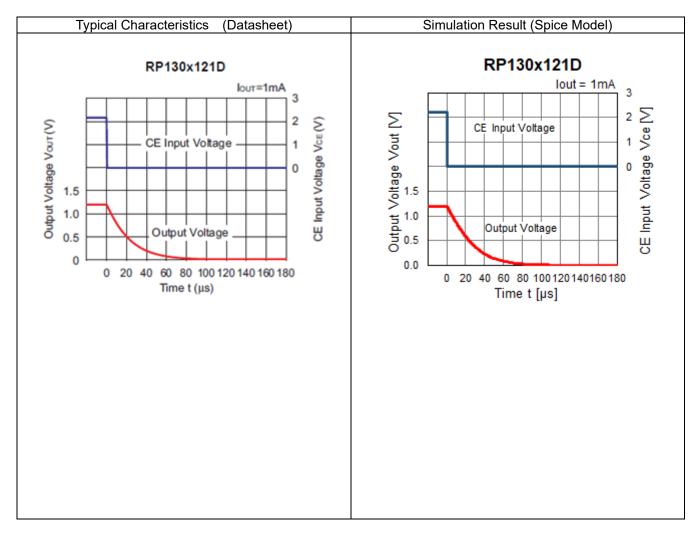
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Characteristic Data

Turn Off Speed with CE pin



Simulation Result

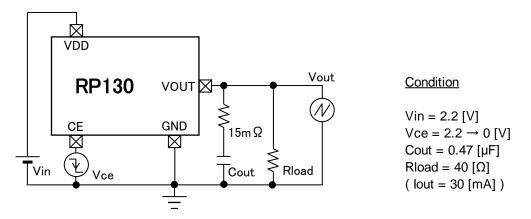


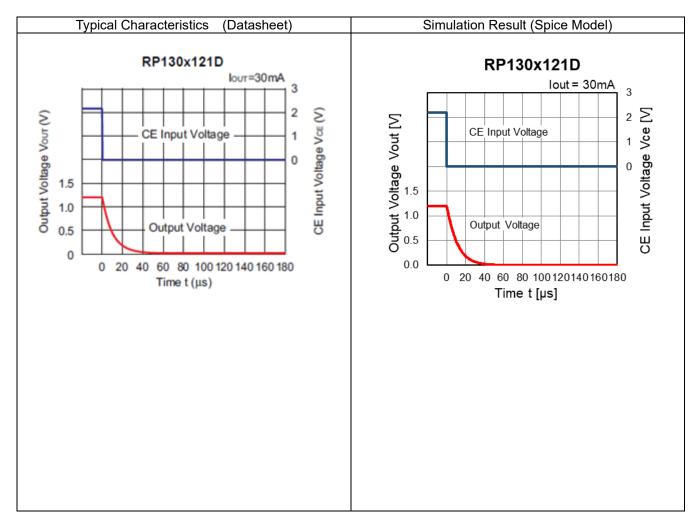
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